IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of JOHN WHITE

Serial No.

10/025,866

Group Art Unit:

2881

Filed: December 26, 2001

Examiner:

For:

ENHANCED LINK OPERATION OF DIRECTLY MODULATED LASERS USING GAIN-

COUPLED GRATINGS

INFORMATION DISCLOSURE STATEMENT

This Information Disclosure Statement is being filed in the manner prescribed by 37 CFR 1.97(b)

- (d) to satisfy the duty under 37 CFR 1.56 to disclose to the Office information, known to

individuals associated with the filing and prosecution of the subject application, which is

/ material to the examination of the application.

In accordance with 37 CFR 1.97(g) and (h), this statement is not to be construed as a

representation that a search has been made or an admission that the information cited herein is, or

is considered to be, material to patentability as defined in 37 CFR 1.56(b).

This information disclosure statement is being filed within three months of the filing date of a

national application, within three months of the date of entry of the national stage as set forth in

37 CFR 1.491 in an international application; or before the mailing date of a first official action

on the merits and therefore applicant respectfully requests consideration under 37 CFR 1.97(b).

In compliance with 37 CFR 1.98(a)(1), a list of all patents, publications or other information

submitted for consideration by the Office is hereby provided by way of the attached Form PTO

1449.

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In compliance with 37 CFR 1.98(a)(2), also enclosed is a legible copy of:

i) each United States and foreign patent;

ii) each publication or that portion which caused it to be listed; and

iii) all other information or that portion which caused it to be listed, excluding any

copies of a United States patent application.

It is respectfully requested that the information be expressly considered by the Examiner and that

the references be made of record and appear among the "References Cited" on any patent to issue

therefrom.

The Patent Office is hereby authorized to charge any deficiency, or credit any overpayment in

fees to Deposit Account Number 19-2550.

Respectfully submitted,

Dated: March 14, 2002

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Encls.:

Form PTO-1449

All references listed on Form PTO-1449

Acknowledgement card

Form PTO-1449 (Modified)

LIST OF PATENTS AND PUBLICATION FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)

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Serial No. 10/025,866

Applicant John White

Filing Date December 26, 2001

Group 2881

REFERENCE DESIGNATION U.S. PATENT DOCUMENTS

- 1	EXAM. INIT.		 DO	CUM	ENT N	NUMB	ER	DATE	NAME	CLASS	SUB CLASS	FIL.DATE IF APPROPRIATE
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FOREIGN PATENT DOCUMENTS

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OTHER ART (including Author, Title, Date, Pertinent Pages, Etc.)

	OTHER ART (including Author, Title, Date, Pertinent Pages, Etc.)
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AN	Yang S. et al: "Enhanced Performance of Uncooled Strongly-Gain-Coupled MQW DFB Lasers in 10Gb/s Link Applications", paper presented at European Conference for Optical Communications, Fall 2001
EXAMINER	DATE CONSIDERED

EXAMINER:

Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.